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	Applicant(s): Hai-Zhi SONG	
	Filing Date: February 20, 2004	Group Art Unit: Not Yet Assigned


U.S. PATENT DOCUMENTS

Examiner Initial	Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
<u>TD</u>	AA	6,335,245	B.G. Park et al.			01/01/02
<u>TD</u>	AB					

FOREIGN PATENT DOCUMENTS

	Document No.	Date	Country	Translation (Yes or No)	
<u>TD</u>	AC	6-196720	07/15/94	Japan	Yes-Abstract
<u>TD</u>	AD	2002-518851	06/25/02	Japan	No-Corresponds to WO 99/66562
<u>TD</u>	AE	10-303408	11/13/98	Japan	Yes-Abstract
<u>TD</u>	AF	11-150261	06/02/99	Japan	Yes-Abstract
<u>TD</u>	AG	5-211342	08/20/93	Japan	Yes-Abstract
<u>TD</u>	AH	2000-91451	03/31/00	Japan	Yes-Abstract
<u>TD</u>	AI	2001-7315	01/12/01	Japan	Yes-Abstract

OTHER DOCUMENTS

<u>TD</u>	AJ	U.F. Keyser et al.; "Fabrication of a single-electron transistor by current-controlled local oxidation of a two-dimensional electron system"; <i>Applied Physics Letters</i> ; Vol. 76; No. 4; January 24, 2000; pp. 457-459.
<u>TD</u>	AK	T. Fujisawa et al.' "Transient current spectroscopy of a quantum dot in the Coulomb blockade regime"; <i>Physical Review B</i> ; Vol. 63; 081304(R); 2001; 4 pages.
<u>TD</u>	AL	Abstract of WO 99/66562 published December 23, 1999/Corresponds to Japanese document number 2002-518851.
Examiner		
Date Considered	12/15/04	